NSN 5961-00-998-4570

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View Online at https://aerobasegroup.com/nsn/5961-00-998-4570	
Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inches and 0.260 inches	
Terminal Length:	
Between 0.500 inches and 0.750 inches	
Overall Diameter:	
Between 0.335 inches and 0.370 inches	
Internal Configuration:	
Junction contact	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
175.0 collector to base voltage/static/emitter open and 175.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage	ge
static, collector open	
Current Rating Per Characteristic:	
1.00 amperes source cutoff current	
Power Rating Per Characteristic:	
5.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: pnp	
Test Data Document:	
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification	n
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain	
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Specification Data:	
81349-mil-prf-19500/357 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	

Nic

Demilitarization:

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Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.